KS54HCTLS / KS74HCTLS 399

Quad 2-Port Registers

FEATURES

- **Function, pin-out, speed and drive compatibility with 54/74LS logic family**
- **Low power consumption characteristic of CMOS**
- **High-Drive-Current outputs:**
  I_{OL} = 8 mA @ V_{OL} = 0.5V
- **Inputs and outputs interface directly with TTL, NMOS and CMOS devices**
- **Wide operating voltage range: 4.5V to 5.5V**
- **Characterized for operation over industrial and military temperature ranges:**
  KS74HCTLS: −40°C to +85°C
  KS54HCTLS: −55°C to +125°C
- **Package options include plastic "small outline" packages, standard plastic and ceramic 300-mil DIPs**

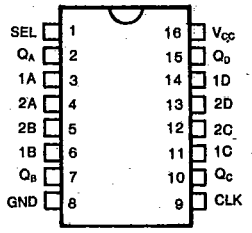
DESCRIPTION

These are high-speed quad 2-port registers. They are the logical equivalent of a quad 2-input multiplexer followed by a quad 4-bit edge-triggered register. A common select input (SEL) selects between two 4-bit input ports. The selected data is transferred to the output register on the low-to-high transition of the clock input.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

PIN CONFIGURATION



FUNCTION TABLE

Inputs			Output
SEL	Port 1	Port 2	Q
l	l	X	L
l	h	X	H
h	X	l	L
h	X	h	H

l = Low Voltage Level one setup time prior to the low-to-high clock transition
h = High Voltage Level one setup time prior to the low-to-high clock transition

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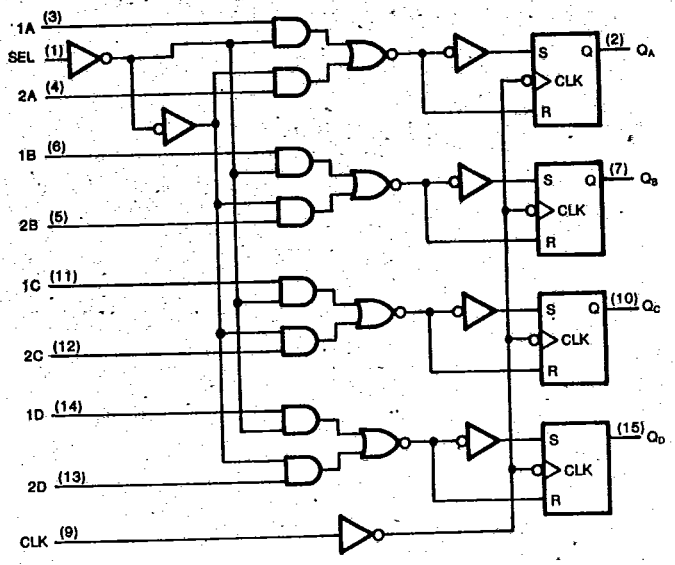
LOGIC DIAGRAM



Absolute Maximum Ratings*

Supply Voltage Range V_{CC} . . . . . −0.5V to +7V
DC Input Diode Current, I_{IK}
(V_I < −0.5V or V_I > V_{CC} +0.5V) . . . . . ±20 mA
DC Output Diode Current, I_{OK}
(V_O < −0.5V or V_O > V_{CC} +0.5V) . . . . ±20 mA
Continuous Output Current Per Pin, I_O
(−0.5V < V_O < V_{CC} +0.5V) . . . . . ±35 mA
Continuous Current Through
V_{CC} or GND pins . . . . . ±125 mA
Storage Temperature Range, T_{stg} . . . −65°C to +150°C
Power Dissipation Per Package, P_d† . . . . . 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:
Plastic Package (N): −12mW/°C from 65°C to 85°C
Ceramic Package (J): −12mW/°C from 100°C to 125°C

Recommended Operating Conditions

Supply Voltage, V_{CC} . . . . . 4.5V to 5.5V
DC Input & Output Voltages*, V_{IN}, V_{OUT} . . 0V to V_{CC}
Operating Temperature
Range KS74HCTLS: −40°C to +85°C
KS54HCTLS: −55°C to +125°C
Input Rise & Fall Times, t_r, t_f . . . . . Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

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Quad 2-Port Registers

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DC ELECTRICAL CHARACTERISTICS (V_{CC}=5V±10% Unless Otherwise Specified)

Characteristic	Symbol	Test Conditions	T_a=25°C	KS74HCTLS T_a=−40°C to +85°C	KS54HCTLS T_a=−55°C to +125°C	Unit
			Typ	Guaranteed Limits		
Minimum High-Level Input Voltage	V_{IH}			2.0	2.0	2.0	V
Maximum Low-Level Input Voltage	V_{IL}			0.8	0.8	0.8	V
Minimum High-Level Output Voltage	V_{OH}	V_{IN}=V_{IH} or V_{IL} I_O=−20μA I_O=−4mA	V_{CC} 4.2	V_{CC} −0.1 3.98	V_{CC} −0.1 3.84	V_{CC} −0.1 3.7	V
Maximum Low-Level Output Voltage	V_{OL}	V_{IN}=V_{IH} or V_{IL} I_O=20μA I_O=4mA I_O=8mA	0	0.1 0.26 0.39	0.1 0.33 0.5	0.1 0.4	V
Maximum Input Current	I_{IN}	V_{IN}=V_{CC} or GND		±0.1	±1.0	±1.0	μA
Maximum Quiescent Supply Current	I_{CC}	V_{IN}=V_{CC} or GND I_{OUT}=0μA		8.0	80.0	160.0	μA
Additional Worst Case Supply Current	ΔI_{CC}	per input pin V_I=2.4V other inputs: at V_{CC} or GND I_{OUT}=0μA		2.7	2.9	3.0	mA

AC ELECTRICAL CHARACTERISTICS (Input t_r, t_f≤6 ns), HCTLS399

Characteristic		Symbol	Conditions†	T_a=25°C V_{CC}=5.0V		KS74HCTLS T_a=−40°C to +85°C V_{CC}=5.0V±10%	KS54HCTLS T_a=−55°C to +125°C V_{CC}=5.0V± 10%	Unit
				Typ	Guaranteed Limits			
Propagation Delay, CLK to Q or $\overline{Q}$		t_{PLH}	C_L=50pF	22	30	37	45	ns
		t_{PHL}		22	30	37	45	
Minimum Pulse Width, CLK High or Low		t_w		10	13	17	20	ns
Minimum Setup Time before CLK†	Data	t_{su}		10	13	17	20	ns
	Word Select			10	13	17	20	
Minimum Hold Time after CLK†	Data	t_h		−3	0	0	0	ns
	Word Select			−3	0	0	0	
Maximum Input Capacitance		C_{IN}		5				pF
Power Dissipation Capacitance*		C_{PD}						pF

* C_{PD} determines the no-load dynamic power dissipation: P_D=C_{PD} V_{CC}^2 f + I_{CC} V_{CC}.

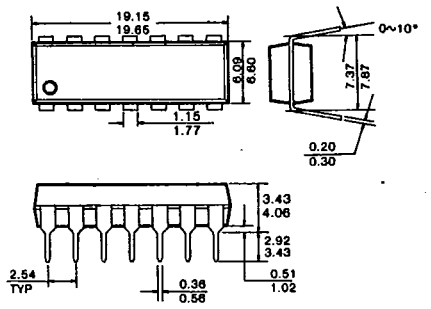
† For AC switching test circuits and timing waveforms see section 2.

PACKAGE DIMENSIONS

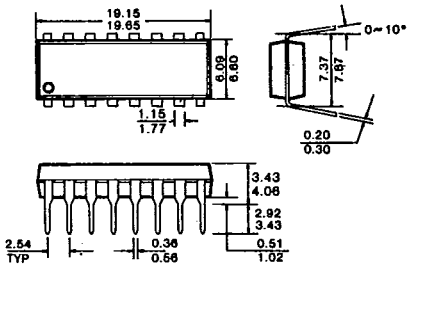
T-90-20

1. PLASTIC PACKAGES

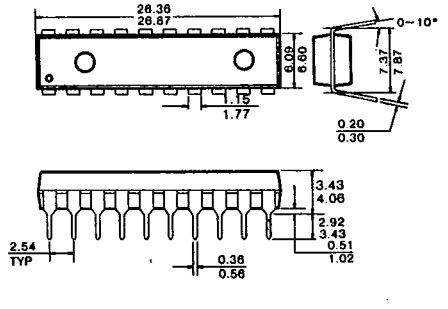
14-Pin Plastic DIP **Units: mm**



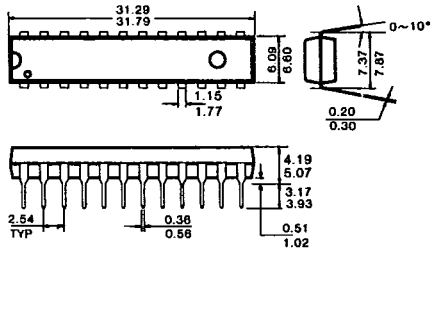
16-Pin Plastic DIP **Units: mm**



20-Pin Plastic DIP **Units: mm**



24-Pin Plastic DIP **Units: mm**



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PACKAGE DIMENSIONS

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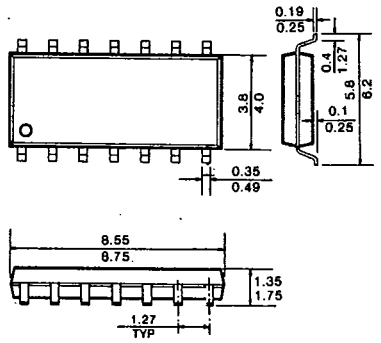
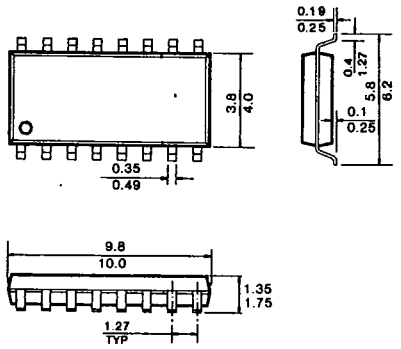
14-Pin SOP

Unit: mm



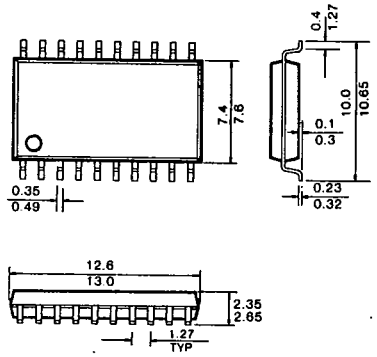
16-Pin SOP

Unit: mm



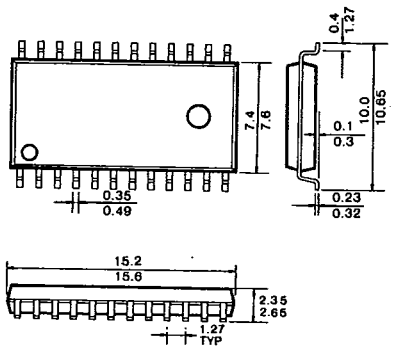
20-Pin SOP

Unit: mm



24-Pin SOP

Unit: mm

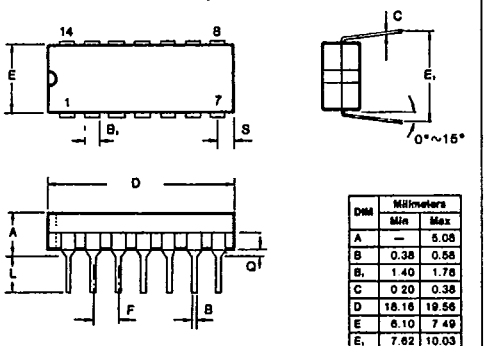


PACKAGE DIMENSIONS

T-90-20

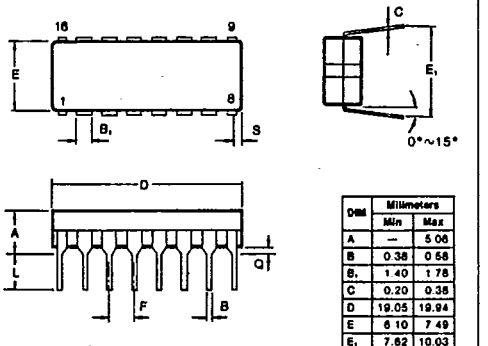
2. CERAMIC PACKAGES

14-Pin Ceramic DIP Units: mm



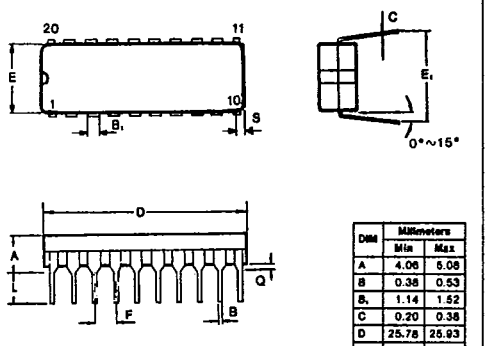
DIM	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B1	1.40	1.78
C	0.20	0.38
D	18.16	19.56
E	6.10	7.49
E1	7.62	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	1.91	2.29

16-Pin Ceramic DIP Units: mm



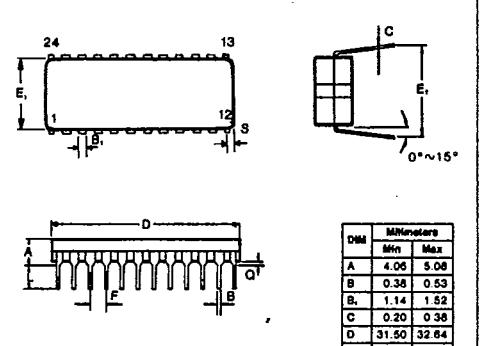
DIM	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B1	1.40	1.78
C	0.20	0.38
D	19.05	19.94
E	6.10	7.49
E1	7.62	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	0.51	1.14

20-Pin Ceramic DIP Units: mm



DIM	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B1	1.14	1.52
C	0.20	0.38
D	25.78	25.93
E	6.10	6.60
E1	7.77	7.98
F	2.54	
L	3.73	4.01
Q	0.38	0.89
S	0.51	1.14

24-Pin Ceramic DIP Units: mm



DIM	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B1	1.14	1.52
C	0.20	0.38
D	31.50	32.64
E	7.24	7.75
E1	7.77	7.98
F	2.54	
L	3.73	4.01
Q	0.508	1.778
S	1.65	1.93

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